

HIGH-SPEED CMOS 8-BIT IDENTITY COMPARATOR

IDT54/74AHCT521

FEATURES:

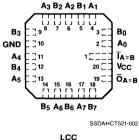
- Equivalent to ALS speeds and output drive over full temperature and voltage supply extremes
- 9ns typical propagation delay
- I_{OL} = 14mA over full military temperature range
- CMOS power levels (5μW typ. static)
- Both CMOS and TTL output compatible
- Substantially lower input current levels than ALS (5μA max.)
- 8-bit identity comparator
- 100% product assurance screening to MIL-STD-883, Class B is available
- JEDEC standard pinout for DIP and LCC

DESCRIPTION:

The IDT54/74AHCT521 is an 8-bit identity comparator built using advanced CEMOS $^{\text{\tiny{M}}}$, a dual metal CMOS technology. The device compares two words of up to eight bits each and provides a LOW output when the two words match bit for bit. The expansion input $\overline{I}_{A=B}$ also serves as an active LOW enable input.

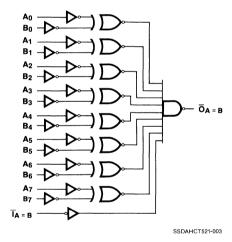
PIN CONFIGURATIONS





LCC TOP VIEW

FUNCTIONAL BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATING(1)

SYMBOL	RATING	COMMERCIAL	MILITARY	UNIT	
V _{TERM}	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	٧	
T _A	Operating Temperature	0 to +70	-55 to +125	°C	
T _{BIAS}	Temperature Under Bias	-55 to +125	-65 to +135	°C	
T _{STG}	Storage Temperature	-55 to +125	-65 to +155	°C	
l _{out}	DC Output Current	120	120	mA	

NOTE:

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

 $T_A = 0^{\circ}C$ to +70°C $V_{CC} = 5.0V \pm 5\%$

V_{CC} = 5.0V ± 5% Min. = 4.75V Max. = 5.25V (Commercial) V_{CC} = 5.0V ± 10% Min. = 4.50V Max. = 5.50V (Military)

 T_{A} = -55°C to +125°C $$V_{CC}$$ = 5.0V \pm 10% \$Min. = 4.50V $$V_{LC}$$ = 0.2V

 $V_{HC} = V_{CC} - 0.2V$

SYMBOL	PARAMETER	TEST CO	MIN.	TYP.(2)	MAX.	UNIT		
V _{IH}	Input HIGH Level	Guaranteed Logic	2.0	_		V		
V _{IL}	Input LOW Level	Guaranteed Logic	Guaranteed Logic Low Level			0.8	V	
I _{IH}	Input HIGH Current	V _{CC} = Max., V _{IN} = \	V _{CC} = Max., V _{IN} = V _{CC}			5	μΑ	
I _{IL}	Input LOW Current	V _{CC} = Max., V _{IN} = C	_	_	-5	μΑ		
I _{sc}	Short Circuit Current	V _{CC} = Max. (3)	V _{CC} = Max. (3)			_	mA	
	Output HIGH Voltage	V _{CC} = 3V, V _{IN} = V _{LC}	$V_{CC} = 3V$, $V_{IN} = V_{LC}$ or V_{HC} , $I_{OH} = -32\mu A$					
V			I _{OH} = -300μA	V _{HC}	V _{cc}		v	
V _{OH}		V _{CC} = Min. V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12mA MIL.	2.4	4.3	_		
		VIN - VIH OI VIL	I _{OH} = -15mA COM'L.	2.4	4.3	_		
	Output LOW Voltage	V _{CC} = 3V, V _{IN} = V _{LC}	$V_{CC} = 3V$, $V_{IN} = V_{LC}$ or V_{HC} , $I_{OL} = 300 \mu A$		GND	V _{LC}		
V			I _{OL} = 300μA		GND	V _{LC}	v	
V _{OL}		$V_{CC} = Min.$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 14mA MIL.	_	_	0.4] V	
		VIN - VIH OF VIL	I _{OL} = 24mA COM'L.	_	_	0.5		

NOTES:

- 1. For conditions shown as max, or min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed one second.

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

POWER SUPPLY CHARACTERISTICS

 $V_{LC} = 0.2V$; $V_{HC} = V_{CC} - 0.2V$

SYMBOL	PARAMETER	TEST CON	MIN.	TYP.(2)	MAX.	UNIT	
Icca	Quiescent Power Supply Current	$\begin{aligned} & V_{CC} = Max. \\ & V_{IN} \ge V_{HC}; \ V_{IN} \le V_{LC} \\ & f_i = 0 \end{aligned}$	$V_{IN} \ge V_{HC}; V_{IN} \le V_{LC}$		0.001	1.5	mA
I _{CCT}	Power Supply Current Per TTL Inputs HIGH	V _{CC} = Max. V _{IN} = 3.4V ⁽³⁾	V _{CC} = Max. V _{IN} = 3.4V ⁽³⁾		0.5	1.6	mA
I _{CCD}	Dynamic Power Supply Current	V _{CC} = Max. Outputs Open One Input Toggling 50% Duty Cycle	$ V_{IN} \ge V_{HC} $ $V_{IN} \le V_{LC} $		0.15	0.25	mA/ MHz
	Total Power Supply ⁽⁴⁾ Current	V _{CC} = Max. Outputs Open	$ \begin{aligned} & V_{\text{IN}} \geq V_{\text{HC}} \\ & V_{\text{IN}} \leq V_{\text{LC}} \text{ (AHCT)} \end{aligned} $	_	0.15	1.8	mA
Icc		f _i = 1.0MHz 50% Duty Cycle	V _{IN} = 3.4V or V _{IN} = GND	_	0.4	2.6	

NOTES:

- 1. For conditions shown as max. or min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
- 3. Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
- 4. I_{CC} = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}
 - $I_{CC} = I_{CCQ} + I_{CCT}D_HN_T + I_{CCD} (f_{CP}/2 + f_iN_i)$
- I_{CCQ} = Quiescent Current
- I_{CCT} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
- D_H = Duty Cycle for TTL Inputs High
- N_T = Number of TTL Inputs at D_H
- I_{CCD} = Dynamic Current caused by an Input Transition pair (HLH or LHL)
- f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
 - f_i = Input Frequency
- N_i = Number of Inputs at f_i

All currents are in milliamps and all frequencies are in megahertz.

DEFINITION OF FUNCTIONAL TERMS

PIN NAMES	DESCRIPTION			
A_0-A_7 B_0-B_7 $\overline{I}_{A=B}$ $\overline{O}_{A=B}$	Word A inputs Word B inputs Expansion or Enable Input (Active LOW) Identity Output (Active Low)			

TRUTH TABLE

INPUTS		OUTPUT		
Ī _{A = B}	A, B	O _{A = B}		
L	A = B*	L		
L	A≠B	Н		
Н	A = B*	Н		
Н	A≠B	Н		

H = HIGH Voltage Level

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

SYMBOL	PARAMETER	CONDITION	TYPICAL	COMMERCIAL		MILITARY		UNITS
	raname ren	CONDITION	TIFICAL	MIN.	MAX.	MIN.	MAX.	O.W.13
t _{PLH} t _{PHL}	Propagation Delay A_N or B_N to $\overline{O}_{A=B}$	$C_L = 50 \text{ pf}$ $R_L = 500 \Omega$	9.0	_	13.0		17.0	ns
t _{PLH} t _{PHL}	Propagation Delay		5.0	_	12.0		11.0	ns

L = LOW Voltage Level $^{\star}A_0 = B_0$, $A_1 = B_1$, $A_2 = B_2$, etc.